

# Xiaomu Wang

## List of Publications by Year in descending order

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54  
papers

6,588  
citations

147726  
31  
h-index

214721  
47  
g-index

55  
all docs

55  
docs citations

55  
times ranked

9577  
citing authors

#	ARTICLE	IF	CITATIONS
1	Highly anisotropic and robust excitons in monolayer black phosphorus. <i>Nature Nanotechnology</i> , 2015, 10, 517-521.	15.6	1,204
2	High-responsivity graphene/silicon-heterostructure waveguide photodetectors. <i>Nature Photonics</i> , 2013, 7, 888-891.	15.6	731
3	Room temperature high-detectivity mid-infrared photodetectors based on black arsenic phosphorus. <i>Science Advances</i> , 2017, 3, e1700589.	4.7	419
4	Black Arsenicâ€“Phosphorus: Layered Anisotropic Infrared Semiconductors with Highly Tunable Compositions and Properties. <i>Advanced Materials</i> , 2015, 27, 4423-4429.	11.1	378
5	Black Phosphorus Radio-Frequency Transistors. <i>Nano Letters</i> , 2014, 14, 6424-6429.	4.5	307
6	Single-nanowire spectrometers. <i>Science</i> , 2019, 365, 1017-1020.	6.0	291
7	Planar carbon nanotubeâ€“graphene hybrid films for high-performance broadband photodetectors. <i>Nature Communications</i> , 2015, 6, 8589.	5.8	258
8	A self-powered high-performance graphene/silicon ultraviolet photodetector with ultra-shallow junction: breaking the limit of silicon?. <i>Npj 2D Materials and Applications</i> , 2017, 1, .	3.9	211
9	Stacked 2D materials shed light. <i>Nature Materials</i> , 2015, 14, 264-265.	13.3	203
10	Optical properties of black phosphorus. <i>Advances in Optics and Photonics</i> , 2016, 8, 618.	12.1	203
11	A light-stimulated synaptic device based on graphene hybrid phototransistor. <i>2D Materials</i> , 2017, 4, 035022.	2.0	186
12	Interlayer interactions in anisotropic atomically thin rhenium diselenide. <i>Nano Research</i> , 2015, 8, 3651-3661.	5.8	159
13	Observation of ballistic avalanche phenomena in nanoscale vertical InSe/BP heterostructures. <i>Nature Nanotechnology</i> , 2019, 14, 217-222.	15.6	153
14	Defect Engineering for Modulating the Trap States in 2D Photoconductors. <i>Advanced Materials</i> , 2018, 30, e1804332.	11.1	146
15	Novel Field-Effect Schottky Barrier Transistors Based on Graphene-MoS2 Heterojunctions. <i>Scientific Reports</i> , 2014, 4, 5951.	1.6	134
16	Graphene Hybrid Structures for Integrated and Flexible Optoelectronics. <i>Advanced Materials</i> , 2020, 32, e1902039.	11.1	127
17	Synthesis of thin-film black phosphorus on a flexible substrate. <i>2D Materials</i> , 2015, 2, 031002.	2.0	124
18	A spectrally tunable all-graphene-based flexible field-effect light-emitting device. <i>Nature Communications</i> , 2015, 6, 7767.	5.8	113

#	ARTICLE	IF	CITATIONS
19	High-Performance Graphene Devices on SiO <sub>2</sub> /Si Substrate Modified by Highly Ordered Self-Assembled Monolayers. <i>Advanced Materials</i> , 2011, 23, 2464-2468.	11.1	101
20	Band Gap Opening of Bilayer Graphene by F4-TCNQ Molecular Doping and Externally Applied Electric Field. <i>Journal of Physical Chemistry B</i> , 2010, 114, 11377-11381.	1.2	98
21	Graphene Based Non-Volatile Memory Devices. <i>Advanced Materials</i> , 2014, 26, 5496-5503.	11.1	95
22	A MoSe <sub>2</sub> /WSe <sub>2</sub> Heterojunction-Based Photodetector at Telecommunication Wavelengths. <i>Advanced Functional Materials</i> , 2018, 28, 1804388.	7.8	95
23	Quantitative Analysis of Graphene Doping by Organic Molecular Charge Transfer. <i>Journal of Physical Chemistry C</i> , 2011, 115, 7596-7602.	1.5	94
24	Monolithic Full-Stokes Near-Infrared Polarimetry with Chiral Plasmonic Metasurface Integrated Graphene-Silicon Photodetector. <i>ACS Nano</i> , 2020, 14, 16634-16642.	7.3	94
25	Improving the Performance of Graphene Phototransistors Using a Heterostructure as the Light-Absorbing Layer. <i>Nano Letters</i> , 2017, 17, 6391-6396.	4.5	87
26	Observation of a giant two-dimensional band-piezoelectric effect on biaxial-strained graphene. <i>NPG Asia Materials</i> , 2015, 7, e154-e154.	3.8	58
27	Solvent-Based Soft-Patterning of Graphene Lateral Heterostructures for Broadband High-Speed Metal-Semiconductor-Metal Photodetectors. <i>Advanced Materials Technologies</i> , 2017, 2, 1600241.	3.0	53
28	Nanoantenna-Sandwiched Graphene with Giant Spectral Tuning in the Visible-to-Near-Infrared Region. <i>Advanced Optical Materials</i> , 2014, 2, 162-170.	3.6	39
29	An ultrasensitive molybdenum-based double-heterojunction phototransistor. <i>Nature Communications</i> , 2021, 12, 4094.	5.8	37
30	van der Waals Transition-Metal Oxide for Vis-MIR Broadband Photodetection via Intercalation Strategy. <i>ACS Applied Materials &amp; Interfaces</i> , 2019, 11, 15741-15747.	4.0	36
31	Graphene/Metal Contacts: Bistable States and Novel Memory Devices. <i>Advanced Materials</i> , 2012, 24, 2614-2619.	11.1	32
32	Robust Impact-Ionization Field-Effect Transistor Based on Nanoscale Vertical Graphene/Black Phosphorus/Indium Selenide Heterostructures. <i>ACS Nano</i> , 2020, 14, 434-441.	7.3	32
33	Electronic Properties of Graphene Altered by Substrate Surface Chemistry and Externally Applied Electric Field. <i>Journal of Physical Chemistry C</i> , 2012, 116, 6259-6267.	1.5	28
34	Electrically tunable optical properties of few-layer black arsenic phosphorus. <i>Nanotechnology</i> , 2018, 29, 484001.	1.3	28
35	Plasmon Excited Ultrahot Carriers and Negative Differential Photoresponse in a Vertical Graphene van der Waals Heterostructure. <i>Nano Letters</i> , 2019, 19, 3295-3304.	4.5	28
36	Graphene integrated photodetectors and opto-electronic devices – a review. <i>Chinese Physics B</i> , 2017, 26, 034203.	0.7	27

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37	Observation of excitonic series in monolayer and few-layer black phosphorus. <i>Physical Review B</i> , 2020, 101, .	1.1	25
38	Macroscopic assembled graphene nanofilms based room temperature ultrafast mid-infrared photodetectors. <i>InformaAnA-MateriAjly</i> , 2022, 4, .	8.5	24
39	Approaching the Collection Limit in Hot Electron Transistors with Ambipolar Hot Carrier Transport. <i>ACS Nano</i> , 2019, 13, 14191-14197.	7.3	21
40	Homo- and Hetero- p-n Junctions Formed on Graphene Steps. <i>ACS Applied Materials &amp; Interfaces</i> , 2014, 6, 3-8.	4.0	20
41	Highly Sensitive and Ultra-Broadband VO <sub>2</sub> (B) Photodetector Dominated by Bolometric Effect. <i>Nano Letters</i> , 2022, 22, 485-493.	4.5	19
42	On-Chip Measurement of Photoluminescence with High Sensitivity Monolithic Spectrometer. <i>Advanced Optical Materials</i> , 2020, 8, 2000191.	3.6	18
43	Strategies for high performance and scalable on-chip spectrometers. <i>JPhys Photonics</i> , 2021, 3, 012006.	2.2	15
44	Photoresponsivity of an all-semimetal heterostructure based on graphene and WTe <sub>2</sub> . <i>Scientific Reports</i> , 2018, 8, 12840.	1.6	14
45	Carrier sheet density constrained anomalous current saturation of graphene field effect transistors: kinks and negative differential resistances. <i>Nanoscale</i> , 2013, 5, 2811.	2.8	11
46	Single-detector black phosphorus monolithic spectrometer with high spectral and temporal resolution. <i>Applied Physics Letters</i> , 2022, 120, .	1.5	4
47	A multi-frequency wireless passive pressure sensor for TPMS applications. , 2009, , .		2
48	Amplifier high linearization method based on offset cancellation technique. , 2009, , .		1
49	Optimal RF IC design based on Fuzzy Genetic Algorithm. , 2009, , .		1
50	Manipulation of Graphene Properties by Interface Engineering. <i>ECS Transactions</i> , 2011, 37, 133-139.	0.3	1
51	Black Phosphorus Optoelectronics. , 2016, , .		1
52	Light-activated artificial synapses based on graphene hybrid phototransistors. , 2016, , .		1
53	P-N Junction Formation in Electron-beam Irradiated Graphene Step. <i>Materials Research Society Symposia Proceedings</i> , 2012, 1407, 224.	0.1	0
54	Photonic synaptic device capable of optical memory and logic operations. , 2017, , .		0